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SANYO Semiconductor (U.S.A) Corporation CPH6616-TL-E

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Datasheet of CPH6616-TL-E - MOSFET 2N-CH 30V 2.5A CPH6

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Ordering number : ENN8107



SANYO Semiconductors DATA SHEET

CPH6616— General-Purpose Switching Device Applications

Features

· Composite type with 2 MOSFETs contained in a single package, facilitating high-density mounting.

N-Channel Silicon MOSFET

- · Excellent ON-resistance characteristic.
- · Best suited for load switches.
- · 4V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		30	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ΙD		2.5	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	10	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm²X0.8mm)1unit	0.9	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	30			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =30V, V _{GS} =0			1	μΑ
Gate-to-Source Leakage Current	IGSS	VGS=±16V, VDS=0			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =1.5A	1.2	2.0		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=1.5A, VGS=10V		79	105	$m\Omega$
	R _{DS} (on)2	I _D =1A, V _{GS} =4V		150	210	mΩ
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		187		pF
Output Capacitance	Coss	VDS=10V, f=1MHz		40		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		33		pF

Marking: WC Continued on next page.

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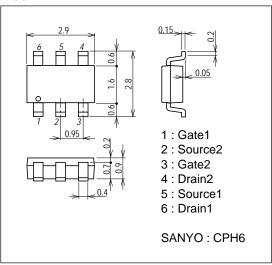
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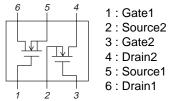
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	O I III
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		7.8		ns
Rise Time	tr	See specified Test Circuit.		18.5		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		22		ns
Fall Time	tf	See specified Test Circuit.		12		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =10V, I _D =2.5A		5.2		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =10V, I _D =2.5A		1		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =10V, I _D =2.5A		0.97		nC
Diode Forward Voltage	V _{SD}	I _S =2.5A, V _{GS} =0		0.9	1.2	V

Package Dimensions

unit: mm 2238

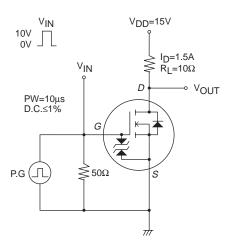


Electrical Connection



Top view

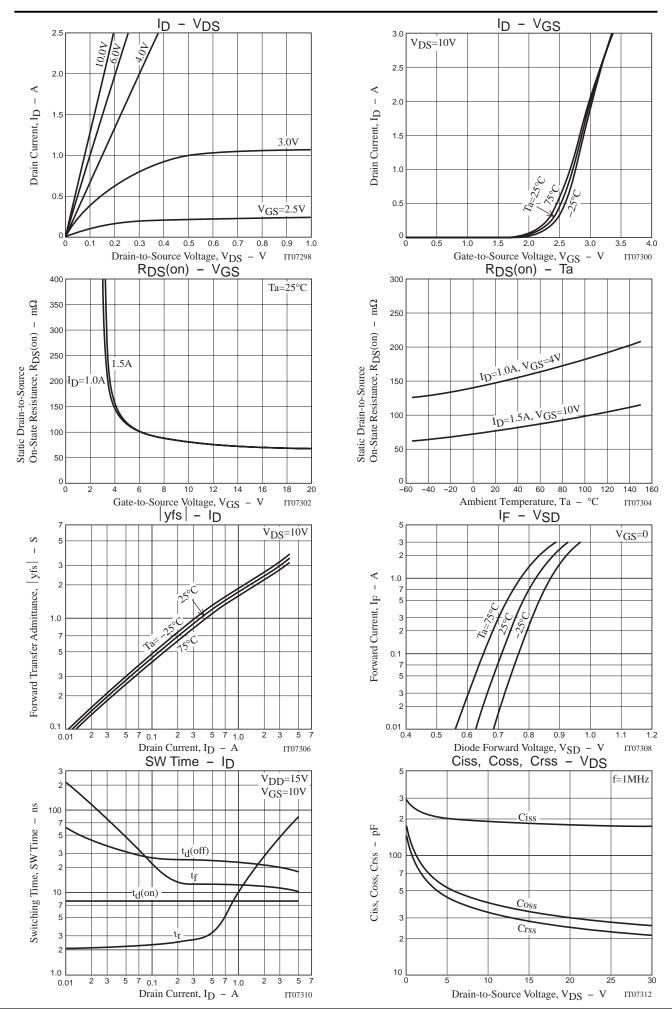
Switching Time Test Circuit



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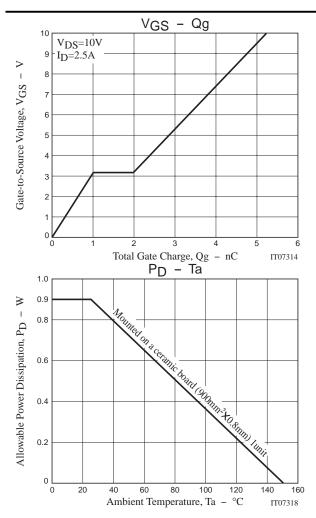


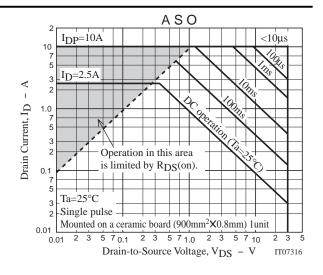
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Note on usage: Since the CPH6616 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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